

LL42 - LL43

FEATURES :

- For general purpose applications.
- This diode features very low turn-on voltage and fast switching. This device is protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- These diodes are also available in the DO-35 case with type designations BAT42 to BAT43
- Pb / RoHS Free

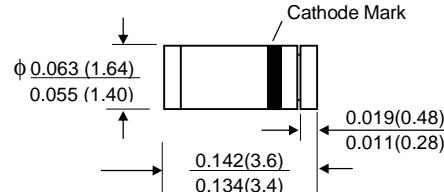
MECHANICAL DATA :

Case: MiniMELF Glass Case (SOD-80C)

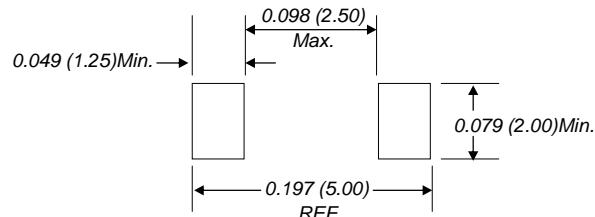
Weight: approx. 0.05g

SCHOTTKY BARRIER DIODES

MiniMELF (SOD-80C)



Mounting Pad Layout



Dimensions in inches and (millimeters)

Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	30	V
Continuous Forward Current	I _F	200 ⁽¹⁾	mA
Repetitive Peak Forward Current at tp < 1s,	I _{FRM}	500 ⁽¹⁾	mA
Forward Surge Current at tp < 10 ms,	I _{FSM}	4 ⁽¹⁾	A
Power Dissipation ,Ta = 65 °C	P _D	200 ⁽¹⁾	mW
Thermal Resistance Junction to Ambient Air	R _{θJA}	300 ⁽¹⁾	°C/W
Junction Temperature	T _J	125	°C
Ambient Operating Temperature Range	T _a	-55 to + 125	°C
Storage temperature range	T _s	-65 to + 150	°C

Note: (1) Valid provided that electrodes are kept at ambient temperature

Electrical Characteristics (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V _{(BR)R}	I _R = 100 μA (pulsed)	30	-	-	V
Reverse Current	I _R	V _R = 25 V	-	-	0.5	μA
Pulse Test tp <300μs , δ <2%		V _R = 25 V , T _J = 100°C	-	-	100	
Forward Voltage LL42 , LL43	V _F	I _F = 200mA	-	-	1.00	
LL42		I _F = 10mA	-	-	0.40	
LL43		I _F = 50mA	-	-	0.65	
LL43		I _F = 2mA	0.26	-	0.33	V
LL43		I _F = 15mA	-	-	0.45	
Diode Capacitance	C _d	V _R = 1V, f = 1MHz	-	7	-	pF
Reverse Recovery Time	T _{rr}	I _F = 10mA, I _R = 10mA , to I _R = 1mA, R _L = 100Ω	-	-	5	ns